

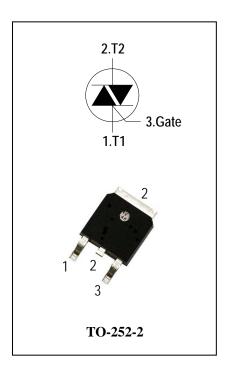
3 Quadrants Triacs

General Description

High current density due to mesa technology . the ADS8C triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners,Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers.

Features

- ◆ Repetitive Peak Off-State Voltage: 600Vand800V
- ◆ R.M.S On-State Current (I_{T(RMS)}= 8A)
- ◆ High Commutation dv/dt
- ◆ These Devices are Pb-Free and are RoHS Compliant



Absolute Maximum Ratings

Symbol	Items	Conditions		Ratings	Unit
V_{DRM}	Depotitive Deals Off State Voltage	Ti = 25°C	ADS8C60E	600	V
V_{RRM}	Repetitive Peak Off-State Voltage	Tj = 25°C	ADS8C80E	800	V
$I_{T(RMS)}$	R.M.S On-State Current	T _C = 110 °C		8	А
I _{TSM}	Surge On-State Current	tp=20ms(50Hz)/tp=16.7ms(60Hz)		80/84	Α
l ² t	I ² t for fusing	tp=10ms		36	A ² s
-11/-14	Critical rate of rise of on-state F = 120 Hz Tj = 125°C			50	Δ /
dl/dt	current	I _G = 2 x I _{GT} , tr ≤ 100 ns	50	A/µs	
I_{GM}	Peak Gate Current	tp = 20 μs Tj = 125°C		4	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=125°C)			1	W
P_GM	Peak Gate Power Dissipation(tp=20us,Tj=125°C)			10	W
Tj	Operating Junction Temperature			- 40 ~ 125	°C
T _{STG}	Storage Temperature			- 40 ~ 150	°C



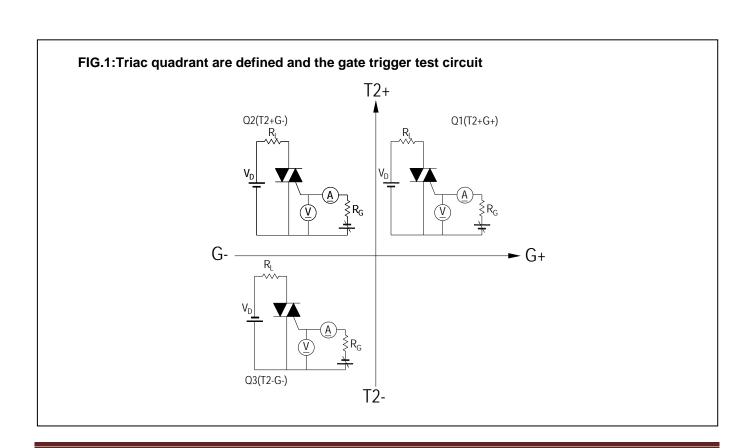


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Electrical Characteristics (Tj = 25°C unless otherwise specified)

Symbol	Items	Conditions		ADS8C60E/80E				Unit	
					Т	S	Blank	В	
I _{DRM}	Peak Forward Reverse Blocking		V _{DRM} = V _{RRM} , Tj = 25°C	N.4	5			uA	
I _{RRM}	Current		$V_{DRM} = V_{RRM}$, $Tj = 125$ °C	Max.	1			mA	
V _{TM}	Peak On-S	tate Voltage	I _{TM} = 11A, t _P = 380 μs	Max.	1.55			٧	
V_{GD}	Q1-Q2-Q3	Non – Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 125^{\circ}\text{C}$	Min.	0.2		٧		
V_{GT}	Q1-Q2-Q3	GateTrigger Voltage	V 40V D 000	Max.	Max. 1.5			٧	
I _{GT}	Q1-Q2-Q3	GateTrigger Current	$V_D = 12V$, $R_L = 33\Omega$	Max.	5	10	35	50	mA
I _H	Q1-Q2-Q3	Holding Current	I _T = 0.1A	Max.	10	15	40	60	mA
	Q1-Q3	Latching Current $I_G = 1.2 I_{GT}$ Max	1 - 401	Max	15	20	50	70	m 1
IL	Q2		iviax.	25	35	60	80	mA	
dV/dt	Critical Rate of Rise of Off-State Voltage		$V_D = 2/3V_{DRM}$ gate open $Tj = 125^{\circ}C$	Min.	50	200	500	1000	V/µs
(dV/dt)c	Rate of Change of Commutating Current,		(dl/dt)c=-3.5A/ms Tj = 125°C	Min.	0.5	1	10	25	V/µs
R _{th(j-c)}	Junction to case (AC)		Max.	1.6			°C/W		
R _{th(j-a)}	Junction to ambient(Copper surface under tab:S=0.5cm²)		Max.	70			°C/W		



ADV

FIG.2: Maximum on-state power dissipation

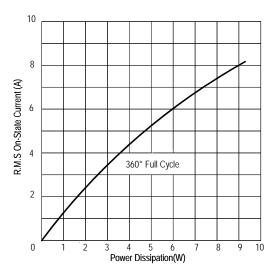


FIG.4: Maximum transient thermal impedance

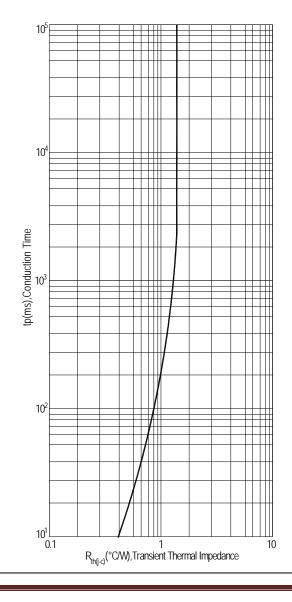


FIG.3: Typical RMS on-state current VS Allowable case Temperature

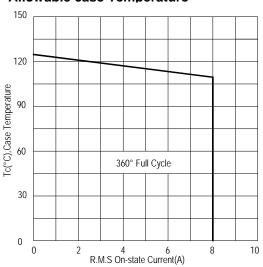


FIG.5: Rated surge on-state current (Non-Repetitive)

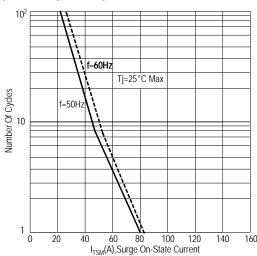


FIG.6: Gate trigger current VS Junction temperature

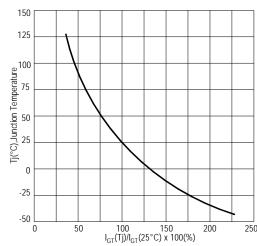




FIG.7:Holding current and Latching current VS Junction temperature

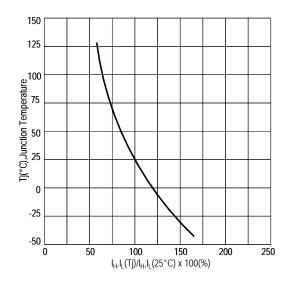


FIG.8: Gate trigger voltage VS Junction temperature

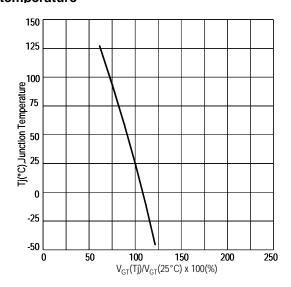
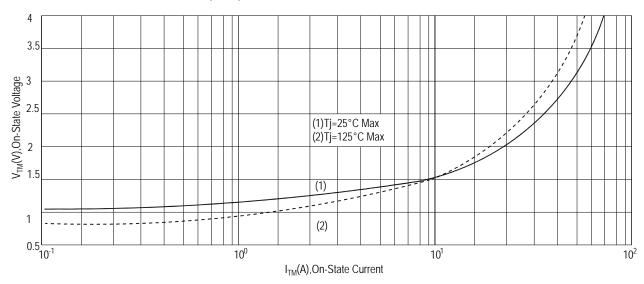


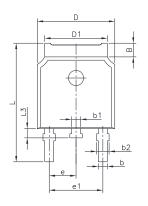
FIG.9: On-state characteristics(Max)

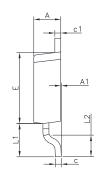


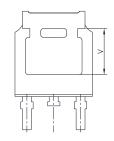
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PACKAGE MECHANICAL DATA TO-252-2 Package Dimension

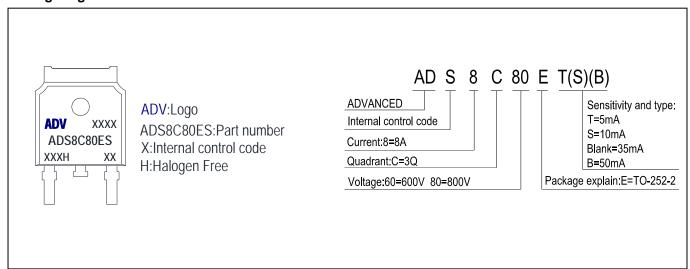






Cumala	Dimer	nsions	Dimensions			
Symb	In Milli	meters	In Inches			
ol	Min.	Max.	Min.	Max.		
Α	2.200	2.400	0.087	0.094		
A1	0.000	0.127	0.000	0.005		
В	1.070	1.220	0.042	0.048		
b	0.720	0.850	0.028	0.033		
b1	0.720	0.850	0.028	0.033		
С	0.450	0.620	0.017	0.024		
c1	0.450	0.620	0.017	0.024		
D	6.350	6.650	0.250	0.262		
D1	5.200	5.400	0.205	0.213		
Е	5.900	6.200	0.232	0.244		
е	2.300 TYP.		0.091 TYP.			
e1	4.500	4.700	0.177	0.185		
L	9.500	10.60	0.374	0.396		
L1	2.550	2.900	0.100	0.114		
L2	1.400	1.780	0.055	0.070		
L3	0.600	0.900	0.024	0.035		
V	3.950 REF.		0.155 REF.			

Making Diagram



Ordering information

Part number	Package	Marking	Packing	Quantity		
ADS8C60E#	TO-252-2	ADS8C60E#	Tube	80pcs		
ADS6C60E#			Embossed tape	2500pcs		
ADC0C00F#	TO-252-2	ADS8C80E#	Tube	80pcs		
ADS8C80E#			Embossed tape	2500pcs		
Note:# = Gate Trigger Current Sensitivity and type						



ADS8C60E/80E

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